

DATA SHEET

FTS2051 — General-Purpose Switching Device Applications

Features

- Low ON-resistance.
- 4V drive.
- Mounting height 1.1mm.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		30	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	۱D		4.5	А
Drain Current (Pulse)	IDP	PW≤10µs, duty cycle≤1%	18	А
Allowable Power Dissipation	PD	Mounted on a ceramic board (1000mm ² X0.8mm)	1.2	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Linit
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	30			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =30V, V _{GS} =0V			1	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±16V, V _{DS} =0V			±10	μΑ
Cutoff Voltage	VGS(off)	VDS=10V, ID=1mA	1.2		2.6	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =3A	2.7	4.5		S
Static Drain-to-Source On-State Resistance	R _{DS} (on) 1	ID=3A, VGS=10V		42	55	mΩ
	R _{DS} (on) 2	ID=1.5A, VGS=4V		66	90	mΩ
Input Capacitance	Ciss	V _{DS} =10V, f=1MHz		460		pF
Output Capacitance	Coss	V _{DS} =10V, f=1MHz		95		pF
Reverse Transfer Capacitance	Crss	V _{DS} =10V, f=1MHz		75		pF

Marking : S2051

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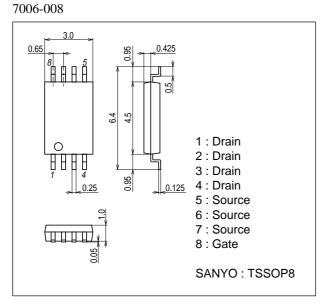
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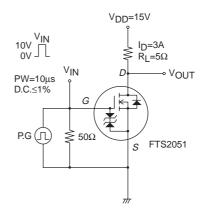
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		11		ns
Rise Time	tr	See specified Test Circuit.		12		ns
Turn-OFF Delay Time	td(off)	See specified Test Circuit.		31		ns
Fall Time	tf	See specified Test Circuit.		18		ns
Total Gate Charge	Qg	V _{DS} =10V, V _{GS} =10V, I _D =4.5A		8.5		nC
Gate-to-Source Charge	Qgs	VDS=10V, VGS=10V, ID=4.5A		1.8		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =10V, V _{GS} =10V, I _D =4.5A		1.3		nC
Diode Forward Voltage	VSD	IS=4.5A, VGS=0V		0.85	1.2	V

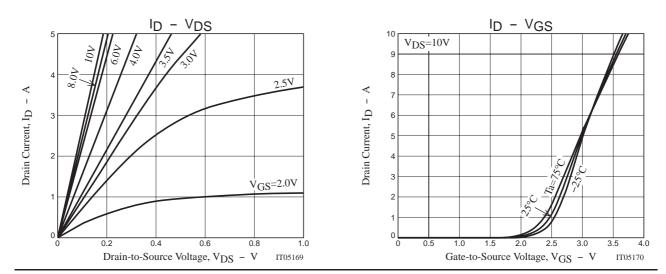
Package Dimensions

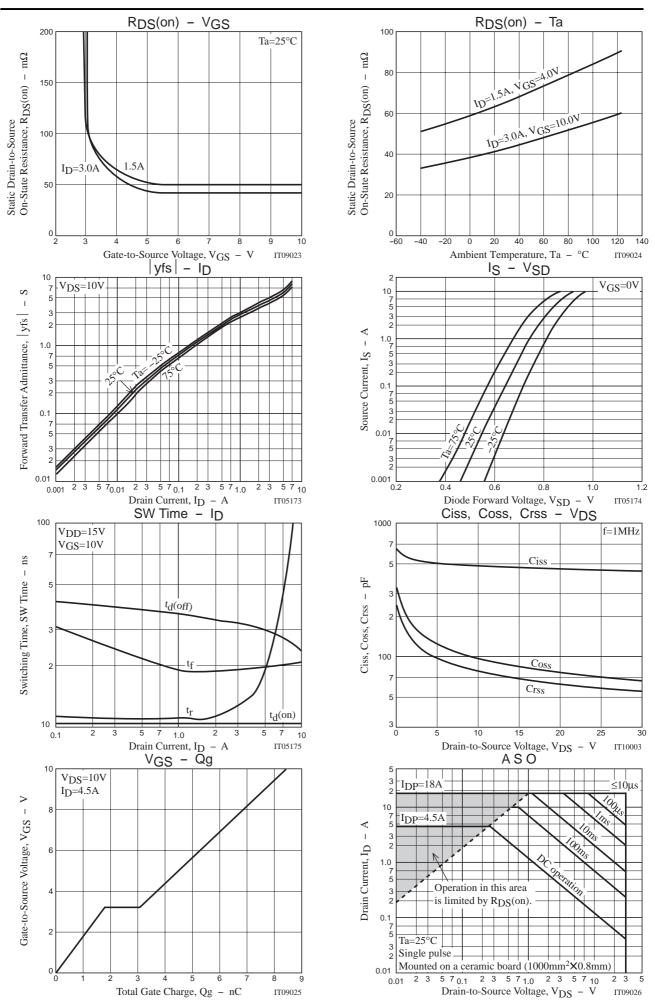
unit : mm

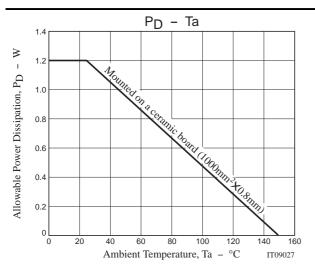


Switching Time Test Circuit









Note on usage : Since the FTS2051 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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